DATA SHEET



# MOS FIELD EFFECT TRANSISTOR

## NP88N055CLE,NP88N055DLE,NP88N055ELE,NP88N055KLE

## SWITCHING N-CHANNEL POWER MOS FET

#### DESCRIPTION

These products are N-channel MOS Field Effect Transistor designed for high current switching applications.

#### FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- $\begin{array}{l} {\sf R}_{\sf DS(on)1}=5.2\ m\Omega \ \ {\sf MAX}.\ ({\sf V}_{\sf GS}=10\ {\sf V},\ {\sf I}_{\sf D}=44\ {\sf A}) \\ {\sf R}_{\sf DS(on)2}=6.3\ m\Omega \ \ {\sf MAX}.\ ({\sf V}_{\sf GS}=5.0\ {\sf V},\ {\sf I}_{\sf D}=44\ {\sf A}) \end{array}$
- Low Ciss: Ciss = 9700 pF TYP.
- Built-in gate protection diode

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Drain to Source Voltage (Vgs = 0 V)             | VDSS     | 55          | V  |
|---|----------|-------------|----|
| Gate to Source Voltage ( $V_{DS} = 0 V$ )       | Vgss     | ±20         | V  |
| Drain Current (DC) Note1                        | ID(DC)   | ±88         | А  |
| Drain Current (pulse) Note2                     | D(pulse) | ±352        | А  |
| Total Power Dissipation ( $T_A = 25^{\circ}C$ ) | P⊤       | 1.8         | W  |
| Total Power Dissipation ( $Tc = 25^{\circ}C$ )  | Pτ       | 288         | W  |
| Channel Temperature                             | Tch      | 175         | °C |
| Storage Temperature                             | Tstg     | -55 to +175 | °C |
| Single Avalanche Current Note3                  | las      | 75/88       | А  |
| Single Avalanche Energy Note3                   | Eas      | 562/232     | mJ |

**Notes 1.** Calculated constant current according to MAX. allowable channel temperature.

- **2.** PW  $\leq$  10  $\mu$ s, Duty cycle  $\leq$  1%
- 3. Starting T\_ch = 25°C, R\_G = 25  $\Omega$  , V\_Gs = 20  $\rightarrow$  0 V (see Figure 4.)

#### THERMAL RESISTANCE

| Channel to Case Thermal Resistance    | $R_{th(ch-C)}$ | 0.52 | °C/W |
|---------------------------------------|----------------|------|------|
| Channel to Ambient Thermal Resistance | Rth(ch-A)      | 83.3 | °C/W |

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## ORDERING INFORMATION

|   | PART NUMBER        | PACKAGE          |  |  |
|---|--------------------|------------------|--|--|
|   | NP88N055CLE        | TO-220AB         |  |  |
|   | NP88N055DLE TO-262 |                  |  |  |
|   | NP88N055ELE        | TO-263 (MP-25ZJ) |  |  |
| ★ | NP88N055KLE        | TO-263 (MP-25ZK) |  |  |

(TO-220AB)



(TO-262)



(TO-263)

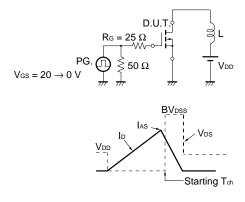


The mark  $\star$  shows major revised points.

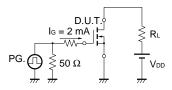
## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

| CHARACTERISTICS                     | SYMBOL          | TEST CONDITIONS   | MIN. | TYP. | MAX.  | UNIT |
|-------------------------------------|-----------------|---|------|------|-------|------|
| Zero Gate Voltage Drain Current     | IDSS            | Vds = 55 V, Vgs = 0 V                                     |      |      | 10    | μA   |
| Gate Leakage Current                | lgss            | $V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$ |      |      | ±10   | μA   |
| Gate to Source Threshold Voltage    | VGS(th)         | $V_{DS} = V_{GS}$ , $I_D = 250 \mu A$                     | 1.5  | 2.0  | 2.5   | V    |
| Forward Transfer Admittance         | y <sub>fs</sub> | Vds = 10 V, Id = 44 A                                     | 38   | 75   |       | S    |
| Drain to Source On-state Resistance | RDS(on)1        | Vgs = 10 V, Id = 44 A                                     |      | 4.1  | 5.2   | mΩ   |
|                                     | RDS(on)2        | Vgs = 5.0 V, Id = 44 A                                    |      | 4.8  | 6.3   | mΩ   |
|                                     | RDS(on)3        | Vgs = 4.5 V, Id = 44 A                                    |      | 5.1  | 6.8   | mΩ   |
| Input Capacitance                   | Ciss            | V <sub>DS</sub> = 25 V                                    |      | 9700 | 14600 | pF   |
| Output Capacitance                  | Coss            | Vgs = 0 V   |      | 1100 | 1700  | pF   |
| Reverse Transfer Capacitance        | Crss            | f = 1 MHz   |      | 490  | 890   | pF   |
| Turn-on Delay Time                  | td(on)          | $V_{DD} = 28 V, I_D = 44 A$                               |      | 37   | 82    | ns   |
| Rise Time                           | tr              | Vgs = 10 V  |      | 22   | 56    | ns   |
| Turn-off Delay Time                 | td(off)         | Rg = 1 Ω  |      | 180  | 360   | ns   |
| Fall Time                           | tr              |   |      | 35   | 88    | ns   |
| Total Gate Charge 1                 | Q <sub>G1</sub> | $V_{DD} = 44 V$ , $V_{GS} = 10 V$ , $I_D = 88 A$          |      | 160  | 240   | nC   |
| Total Gate Charge 2                 | Q <sub>G2</sub> | Vdd = 44 V  |      | 88   | 140   | nC   |
| Gate to Source Charge               | Q <sub>GS</sub> | Vgs = 5.0 V   |      | 27   |       | nC   |
| Gate to Drain Charge                | Qgd             | ID = 88 A   |      | 48   |       | nC   |
| Body Diode Forward Voltage          | VF(S-D)         | IF = 88 A, VGS = 0 V                                      |      | 1.0  |       | V    |
| Reverse Recovery Time               | trr             | IF = 88 A, VGS = 0 V                                      |      | 62   |       | ns   |
| Reverse Recovery Charge             | Qrr             | di/dt = 100 A/µs  |      | 120  |       | nC   |

#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

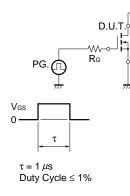


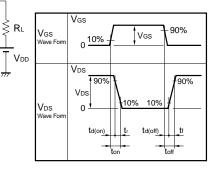
#### **TEST CIRCUIT 3 GATE CHARGE**



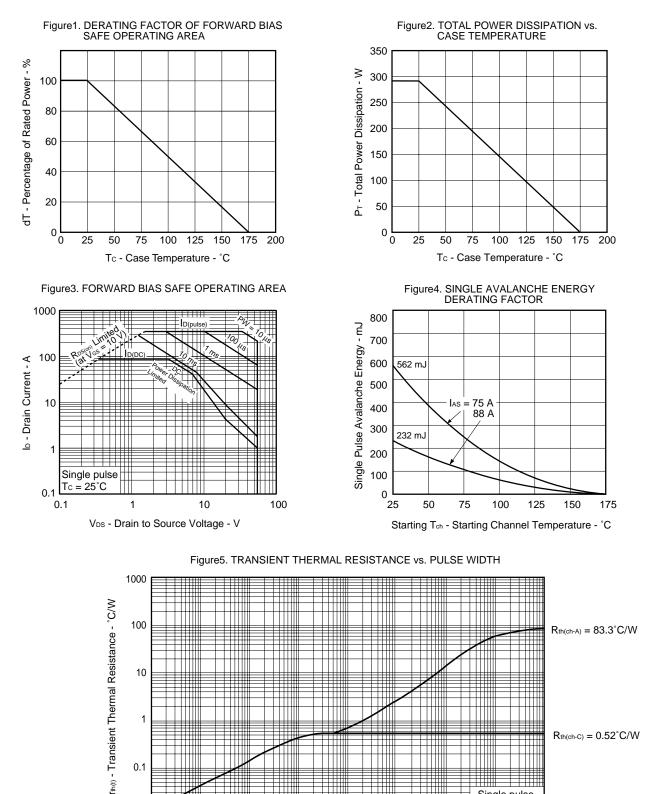
#### **TEST CIRCUIT 2 SWITCHING TIME**

₩





## TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )



100 m

PW - Pulse Width - s

1 m

10 m

 $100 \, \mu$ 

0.01

10*µ* 

1

Ш

10

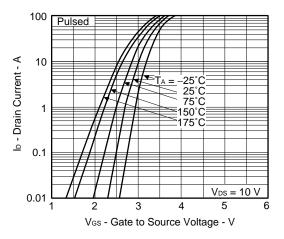
Single pulse

1000

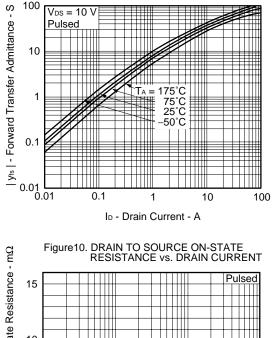
Tc = 25°C

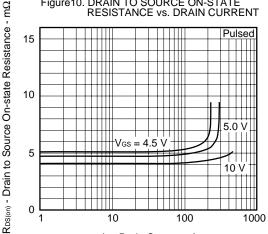
100

Figure6. FORWARD TRANSFER CHARACTERISTICS

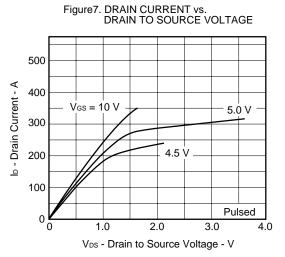








ID - Drain Current - A



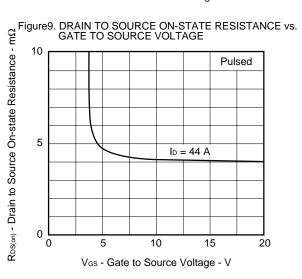
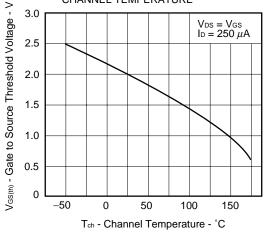
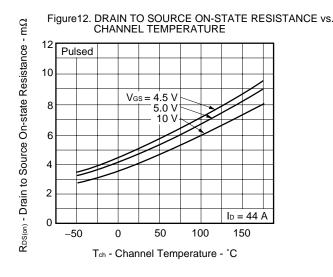


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE





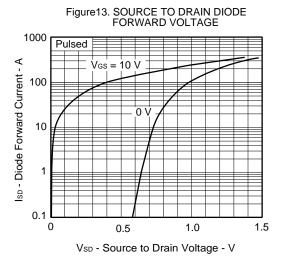
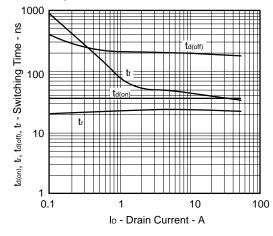
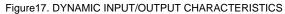
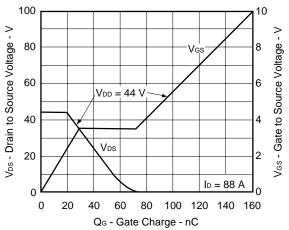
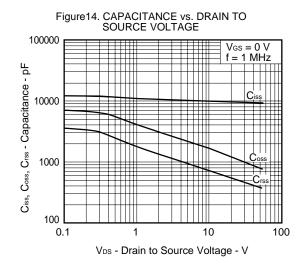


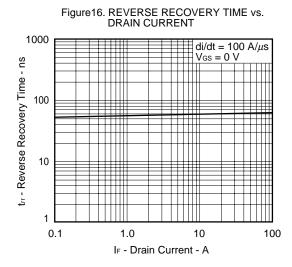
Figure15. SWITCHING CHARACTERISTICS











### PACKAGE DRAWINGS (Unit: mm)

#### 1) TO-220AB (MP-25)

3) TO-263 (MP-25ZJ)

1.0±0.5

<u>1.4±0.2</u>

0.7±0.2

2.54 TYP

10 TYP.

2 3

 $\Box$ 

Δ

8.5±0.2

5.7±0.4

2.54 TYP.

2.8±0.2

0.5RTVP.

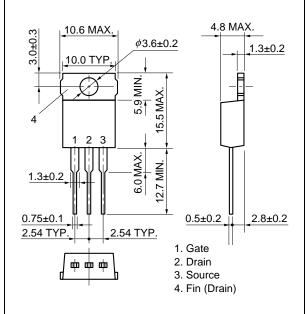
0.8RTYP.

1. Gate

2. Drain

3. Source

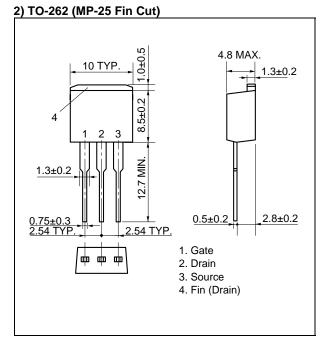
4. Fin (Drain)



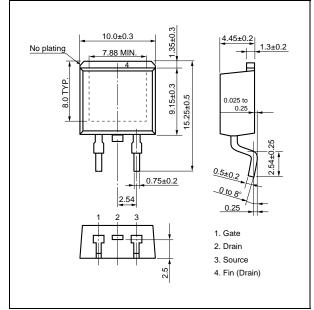
4.8 MAX.

1.3±0.2

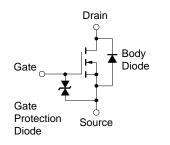
0.5±0.2



#### ★ 4) TO-263 (MP-25ZK)



## EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

[MEMO]

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